1. General description

The HEF4894B-Q100 is a 12-stage serial shift register. It has a storage latch associated with each stage for strobing data from the serial input (D) to the parallel LED driver outputs (QP0 to QP11). Data is shifted on positive-going clock (CP) transitions. The data in each shift register stage is transferred to the storage register when the strobe (STR) input is HIGH. Data in the storage register appears at the output whenever the output enable (OE) input signal is HIGH.

Two serial outputs (QS1 and QS2) are available for cascading a number of HEF4894B-Q100 devices. Serial data is available at QS1 on positive-going clock edges to allow high-speed operation in cascaded systems with a fast clock rise time. The same serial data is available at QS2 on the next negative going clock edge. This is used for cascading HEF4894B-Q100 devices when the clock has a slow rise time.

It operates over a recommended V_{DD} power supply range of 3 V to 15 V referenced to V_{SS} (usually ground). Unused inputs must be connected to V_{DD} , V_{SS} , or another input.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 3.0 V to 15.0 V
- CMOS low power dissipation
- High noise immunity
- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Complies with JEDEC standard JESD 13-B
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V

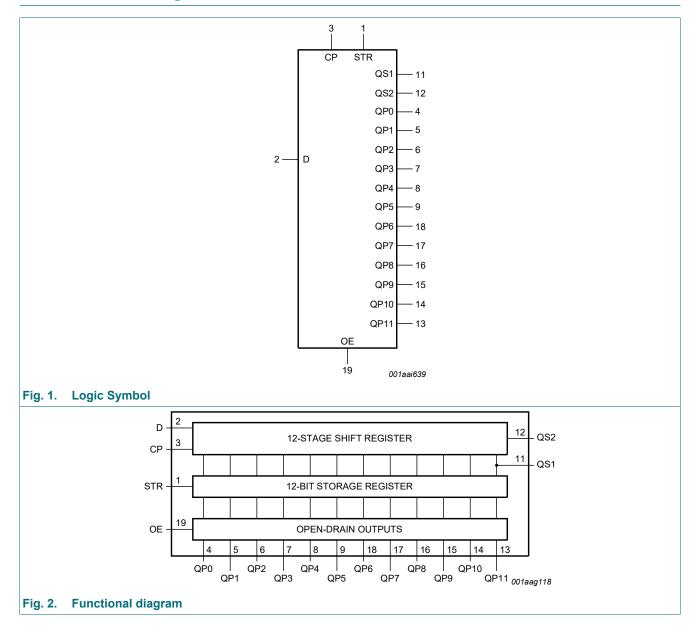
3. Ordering information

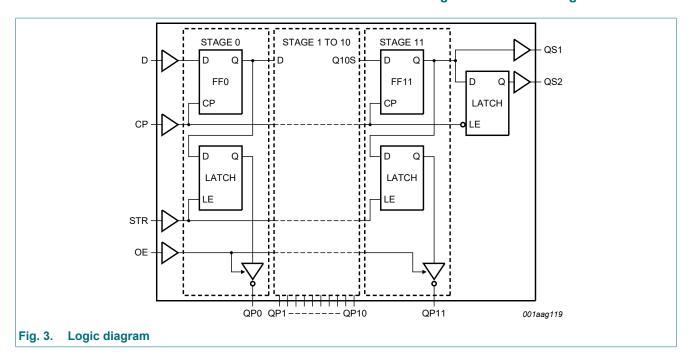
Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
HEF4894BT-Q100	-40 °C to +125 °C	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1
HEF4894BTT-Q100	-40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads; body width 4.4 mm	SOT360-1



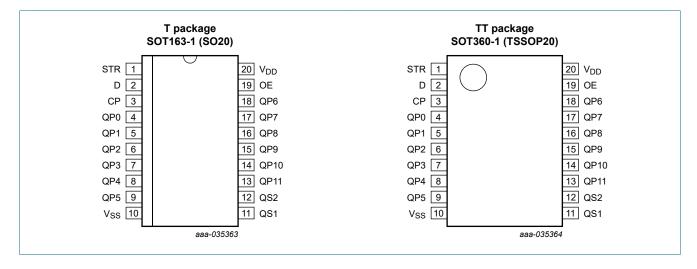
4. Functional diagram





5. Pinning information

5.1. Pinning



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5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
D	2	serial input
QP0 to QP11	4, 5, 6, 7, 8, 9, 18, 17, 16, 15, 14, 13	parallel output
QS1	11	serial output
QS2	12	serial output
СР	3	clock input
STR	1	strobe input
OE	19	output enable input
V_{DD}	20	supply voltage
V _{SS}	10	ground (0 V)

6. Functional description

Table 3. Function table

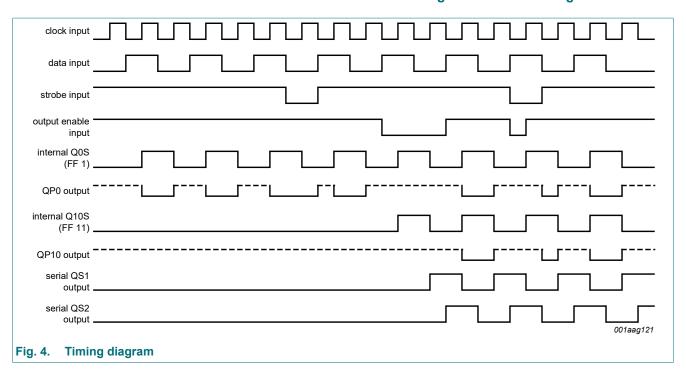
 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ X = don't \ care; \ \uparrow = LOW-to-HIGH \ clock \ transition;$

↓ = HIGH-to-LOW clock transition; Z = high-impedance OFF-state.

At the LOW-to-HIGH clock transition, the information in the 10th register stage is transferred to the 11th register stage and the QS output.

Control		Input	Parallel outp	Parallel output		Serial output		
СР	OE	STR	D	QP0	QPn	QS1[1]	QS2[2]	
↑	L	X	X	Z	Z	Q10S	no change	
\downarrow	L	X	X	Z	Z	no change	Q11S	
↑	Н	L	X	no change	no change	Q10S	no change	
1	Н	Н	L	Z	QPn - 1	Q10S	no change	
↑	Н	Н	Н	L	QPn - 1	Q10S	no change	
\downarrow	Н	Н	Н	no change	no change	no change	Q11S	

- [1] Q10S = the data in register stage 10 before the LOW-to-HIGH clock transition.
- [2] Q11S = the data in register stage 11 before the HIGH-to-LOW clock transition.



7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DD}	supply voltage		-0.5	+18	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{DD} + 0.5 \text{ V}$	-	±10	mA
VI	input voltage		-0.5	V _{DD} + 0.5	V
lok	output clamping current	QSn outputs; $V_O < -0.5 \text{ V or } V_O > V_{DD} + 0.5 \text{ V}$	-	±10	mA
		QPn outputs; V _O < 0.5 V	-	40	mA
I _I	input leakage current		-	±10	mA
Io	output current	QSn outputs	-	±10	mA
		QPn outputs	-	40	mA
T _{stg}	storage temperature		-65	+150	°C
T _{amb}	ambient temperature		-40	+125	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[1] -	500	mW
Р	power dissipation	per output	-	100	mW

^[1] For SOT163-1 (SO20) package: P_{tot} derates linearly with 12.3 mW/K above 109 °C. For SOT360-1 (TSSOP20) package: P_{tot} derates linearly with 10.0 mW/K above 100 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit					
V_{DD}	supply voltage		3	-	15	V					
VI	input voltage		0	-	V_{DD}	V					
T _{amb}	ambient temperature	in free air	-40	-	+125	°C					

HEF4894B_Q100

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Δt/ΔV	input transition rise and fall rate	V _{DD} = 5 V	-	-	3.75	µs/V
		V _{DD} = 10 V	-	-	0.5	µs/V
		V _{DD} = 15 V	-	-	0.08	µs/V

9. Static characteristics

Table 6. Static characteristics

 $V_{SS} = 0 \ V$; $V_{I} = V_{SS} \ or \ V_{DD}$; unless otherwise specified.

Symbol	Parameter	Conditions	V_{DD}	T _{amb} =	-40 °C	T _{amb} =	+25 °C	T _{amb} =	+85 °C	T _{amb} = +125 °C		Unit
				Min	Max	Min	Max	Min	Max	Min	Max	
V_{IH}	HIGH-level	I _O < 1 μΑ	5 V	3.5	-	3.5	-	3.5	-	3.5	-	V
	input voltage		10 V	7.0	-	7.0	-	7.0	-	7.0	-	V
			15 V	11.0	-	11.0	-	11.0	-	11.0	-	V
V_{IL}	LOW-level	I _O < 1 μA	5 V	-	1.5	-	1.5	-	1.5	-	1.5	V
	input voltage	ut voltage	10 V	-	3.0	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	-	4.0	V
V_{OH}	HIGH-level	QSn outputs;	5 V	4.95	-	4.95	-	4.95	-	4.95	-	V
	output voltage	I _O < 1 μA	10 V	9.95	-	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	14.95	-	V
V_{OL}	LOW-level	QSn outputs;	5 V	-	0.05	-	0.05	-	0.05	-	0.05	V
output v	output voltage	age I _O < 1 μA	10 V	-	0.05	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	-	0.05	V
		QPn outputs; I _O < 20 mA	5 V	-	0.75	-	0.75	-	1.5	-	1.5	V
			10 V	-	0.75	-	0.75	-	1.5	-	1.5	V
			15 V	-	0.75	-	0.75	-	1.5	-	1.5	V
I _{OH}	HIGH-level output current	QSn outputs										
		V _O = 2.5 V	5 V	-	-1.7	-	-1.4	-	-1.1	-	-1.1	mA
		V _O = 4.6 V	5 V	-	-0.64	-	-0.5	-	-0.36	-	-0.36	mA
		V _O = 9.5 V	10 V	-	-1.6	-	-1.3	-	-0.9	-	-0.9	mA
		V _O = 13.5 V	15 V	-	-4.2	-	-3.4	-	-2.4	-	-2.4	mA
I _{OL}	LOW-level	QSn outputs										
	output current	V _O = 0.4 V	5 V	0.64	-	0.5	-	0.36	-	0.36	-	mA
		V _O = 0.5 V	10 V	1.6	-	1.3	-	0.9	-	0.9	-	mA
		V _O = 1.5 V	15 V	4.2	-	3.2	-	2.4	-	2.4	-	mA
I _I	input leakage current		15 V	-	±0.1	-	±0.1	-	±1.0	-	±1.0	μΑ
I _{OZ}	OFF-state	QPn output	5 V	-	2	-	2	-	15	-	15	μΑ
	output current	is HIGH;	10 V	-	2	-	2	-	15	-	15	μA
		V _O = 15 V	15 V	-	2	-	2	-	15	-	15	μA
I _{DD}	supply current	I _O = 0 A	5 V	-	5	-	5	-	150	-	150	μA
		-FF.)	10 V	-	10	-	10	-	300	-	300	μA
			15 V	-	20	-	20	-	600	-	600	μA
Cı	input capacitance		-	-	-	-	7.5	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

 V_{SS} = 0 V; T_{amb} = 25 °C unless otherwise specified. For test circuit see Fig. 9.

Symbol	Parameter	Conditions	V_{DD}		Extrapolation formula	Min	Тур	Max	Unit
t _{PHL}	HIGH to LOW	CP to QS1; see Fig. 5	5 V	[1]	132 ns + (0.55 ns/pF)C _L	-	160	320	ns
	propagation delay		10 V		53 ns + (0.23 ns/pF)C _L	-	65	130	ns
	uciay		15 V		37 ns + (0.16 ns/pF)C _L	-	45	90	ns
		CP to QS2; see Fig. 5	5 V		92 ns + (0.55 ns/pF)C _L	-	120	240	ns
			10 V		39 ns + (0.23 ns/pF)C _L	-	50	100	ns
			15 V		32 ns + (0.16 ns/pF)C _L	-	40	80	ns
t _{PLH}	LOW to HIGH	CP to QS1; see Fig. 5	5 V	[1]	102 ns + (0.55 ns/pF)C _L	-	130	260	ns
	propagation delay		10 V		44 ns + (0.23 ns/pF)C _L	-	55	110	ns
	delay		15 V		32 ns + (0.16 ns/pF)C _L	-	40	80	ns
		CP to QS2; see Fig. 5	5 V		102 ns + (0.55 ns/pF)C _L	-	130	260	ns
			10 V		49 ns + (0.23 ns/pF)C _L	-	60	120	ns
			15 V		37 ns + (0.16 ns/pF)C _L	-	45	90	ns
t _{PZL}	OFF-state	CP to QPn; see Fig. 5	5 V			-	240	480	ns
	to LOW propagation		10 V			-	80	160	ns
	delay		15 V			-	55	110	ns
		STR to QPn; see Fig. 6	5 V			-	140	280	ns
			10 V			-	70	140	ns
			15 V			-	55	110	ns
t _{PLZ}	LOW to	CP to QPn; see Fig. 5 and	5 V			-	170	340	ns
	OFF-state	Fig. 6	10 V			-	75	150	ns
	propagation delay		15 V			-	60	120	ns
		STR to QPn; see Fig. 6	5 V			-	100	200	ns
			10 V			-	40	100	ns
			15 V			-	35	70	ns
t _{en}	enable time	OE to QPn; see Fig. 7	5 V	[2]		-	100	200	ns
			10 V			-	55	110	ns
			15 V			-	50	100	ns
t _{dis}	disable time	OE to QPn; see Fig. 7	5 V	[2]		-	80	160	ns
			10 V			-	40	80	ns
			15 V			-	30	60	ns
t _t	transition time	QS1, QS2; see Fig. 5	5 V	[1][3]	35 ns + (1.00 ns/pF)C _L	-	85	170	ns
			10 V		19 ns + (0.42 ns/pF)C _L	-	40	80	ns
			15 V		16 ns + (0.28 ns/pF)C _L	-	30	60	ns
t _W	pulse width	CP; LOW and HIGH;	5 V			60	30	-	ns
		see Fig. 5	10 V			30	15	-	ns
			15 V			24	12	-	ns
		STR; HIGH; see Fig. 6	5 V			80	40	-	ns
			10 V			60	30	-	ns
			15 V			24	12	-	ns

Symbol	Parameter	Conditions	V _{DD}	Extrapolation formula	Min	Тур	Max	Unit
t _{su}	set-up time	D to CP; see Fig. 8	5 V		60	30	-	ns
		10 V		20	10	-	ns	
			15 V		15	5	-	ns
t _h hold time	D to CP; see Fig. 8	5 V		+5	-15	-	ns	
			10 V		20	5	-	ns
			15 V		20	5	-	ns
f _{clk(max)}	maximum	CP; see Fig. 5	5 V		5	10	-	MHz
clock frequency			10 V		11	22	-	MHz
		15 V		14	28	-	MHz	

- [1] The typical values of the propagation delay and transition times are calculated from the extrapolation formulas shown (C_L in pF).
- [2] t_{en} is the same as t_{PZL} and t_{dis} is the same as t_{PLZ} .
- [3] t_t is the same as t_{TLH} and t_{THL} .

Table 8. Dynamic power dissipation

 P_D can be calculated from the formulas shown. V_{SS} = 0 V; t_r = t_f ≤ 20 ns; T_{amb} = 25 °C.

Symbol	Parameter	V_{DD}	Typical formula	Where
P_{D}		5 V	. (0 2)	f _i = input frequency in MHz;
	dissipation	10 V	Pn = 3330 × 1; + / U, × C, J × Vnn - UVV	f _o = output frequency in MHz; C _I = output load capacitance in pF;
		15 V		$\Sigma(f_0 \times C_L)$ = sum of the outputs;
				V _{DD} = supply voltage in V.

10.1. Waveforms and test circuit

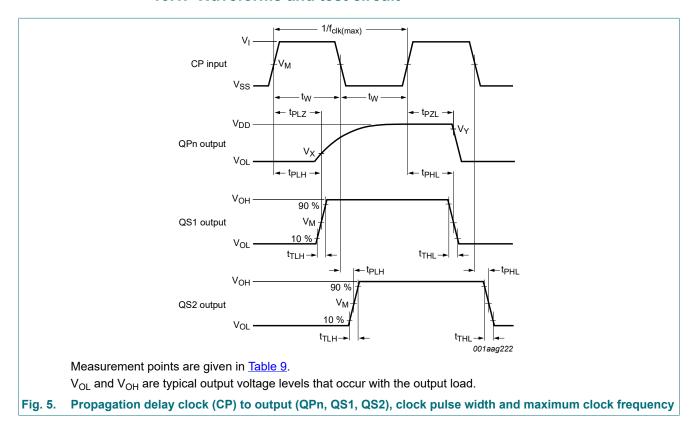


Table 9. Measurement points

Supply	Input	Output				
V_{DD}	V _M	V _M	V _X	V _Y		
5 V to 15 V	0.5V _{DD}	0.5V _{DD}	0.1V _O	0.9V _O		

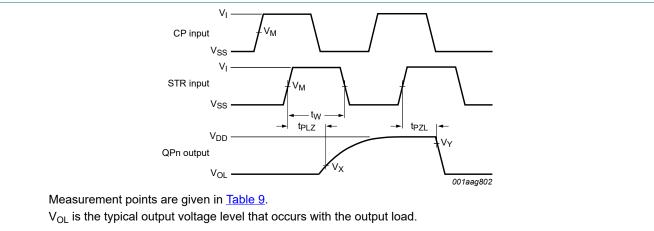
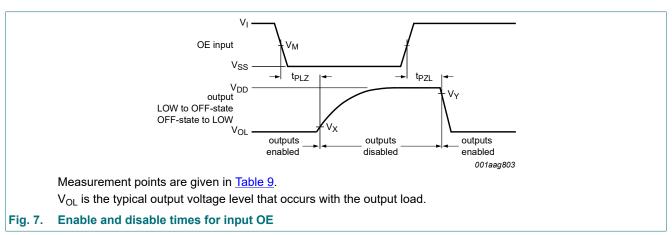
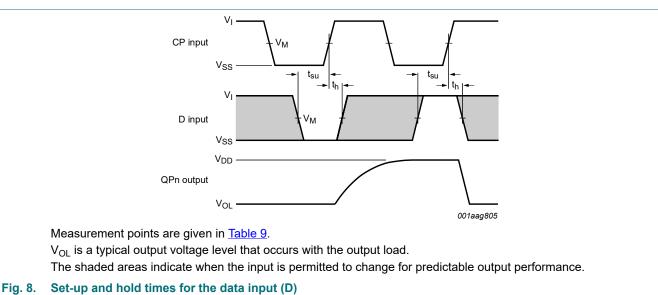
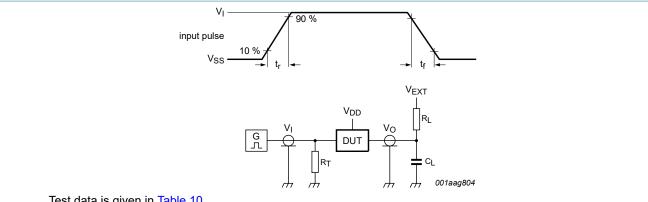


Fig. 6. Strobe (STR) to output (QPn) propagation delays and the strobe pulse width





HEF4894B_Q100



Test data is given in Table 10.

Definitions for test circuit:

R_L = Load resistance;

C_L = load capacitance;

 R_T = Termination resistance should be equal to output impedance of Z_0 of the pulse generator;

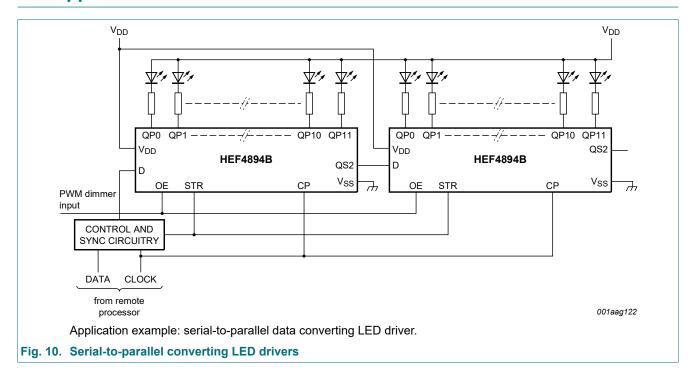
V_{EXT} = External voltage for measuring switching times.

Test circuit for measuring switching times Fig. 9.

Table 10. Test data

Supply Input		V _{EXT}		Load		
V_{DD}	V _I	t _r , t _f	t _{PLZ} , t _{PZL}	t _{PLH} , t _{PHL}	CL	R _L
5 V to 15 V	V_{DD}	≤ 20 ns	V_{DD}	open	50 pF	1 kΩ

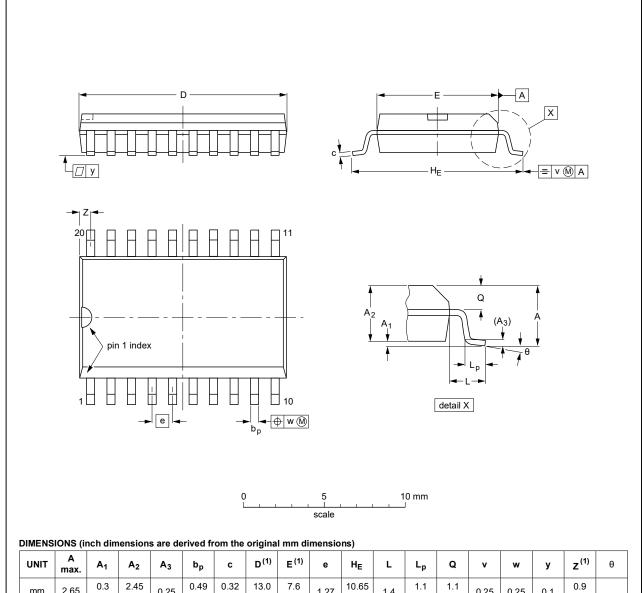
11. Application information



12. Package outline



SOT163-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	z ⁽¹⁾	θ
mm	2.65	0.3 0.1	2.45 2.25	0.25	0.49 0.36	0.32 0.23	13.0 12.6	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8°
inches	0.1	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.51 0.49	0.30 0.29	0.05	0.419 0.394	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	0°

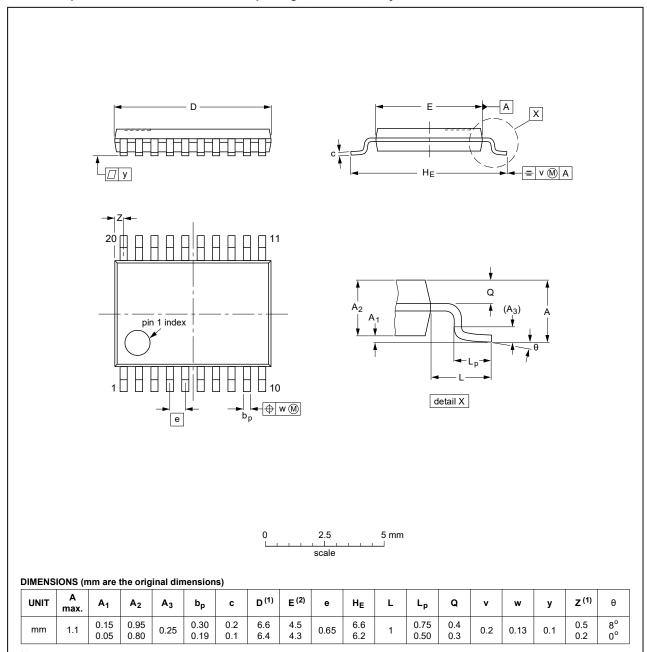
1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT163-1	075E04	MS-013				99-12-27 03-02-19

Fig. 11. Package outline SOT163-1 (SO20)

TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1



Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT360-1		MO-153				99-12-27 03-02-19

Fig. 12. Package outline SOT360-1 (TSSOP20)

13. Abbreviations

Table 11. Abbreviations

Acronym	Description
ANSI	American National Standards Institute
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
ESDA	ElectroStatic Discharge Association
НВМ	Human Body Model
JEDEC	Joint Electron Device Engineering Council
LED	Light Emitting Diode

14. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
HEF4894B_Q100 v.3	20240813	Product data sheet	-	HEF4894B_Q100 v.2
Modifications:	Section 2: E	SD specification updated a	according to the la	atest JEDEC standard.
HEF4894B_Q100 v.2	20211123	Product data sheet	-	HEF4894B_Q100 v.1
Modifications:	guidelines o Legal texts	have been adapted to the i Derating values for P _{tot} tota	new company nar	ne where appropriate.
HEF4894B_Q100 v.1	20120712	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

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